

View Online at <https://aerobasegroup.com/nsn/5961-01-222-8467>

Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.050 inches all semiconductor device diode

Overall Diameter:

0.055 inches all semiconductor device diode

Internal Configuration:

Junction contact all semiconductor device diode

Electrode Internally-electrically Connected To Case:

Collector all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Press fit all semiconductor device diode

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

-10.0 forward voltage, dc all semiconductor device diode

Current Rating Per Characteristic:

100.00 milliamperes forward current, dc all semiconductor device diode

Power Rating Per Characteristic:

100.0 milliwatts total power dissipation all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

125.0 degrees celsius ambient air all semiconductor device diode

Terminal Type And Quantity:

4 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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